

Impedance Spectroscopy Measurements in Perovskite Solar Cells: Device Stability and Noise Reduction

Perovskite solar cells (PSCs) are the most recent newcomers to the photovoltaic field and have attracted huge interest in the past few years due to their high photoconversion efficiencies (higher than 22%)¹ and their relatively easy fabrication process.² Despite that PSCs constitute a category of solar cells with its own peculiarities, earlier reports used perovskites to sensitize wide band gap semiconductors.^{3,4} Undoubtedly, the rapid increase in efficiency experienced by PSCs has much to be thankful for with all of the previous work done on low-temperature processed technologies as sensitized cells or organic photovoltaics. In this sense, it is not surprising to observe that researchers use most of the characterization techniques developed for these former technologies in order to characterize PSCs. However, translation of characterization methods has to take into account the specificities of PSCs to avoid potentially misleading procedures and results. In the case of PSCs, the most archetypical example is the photoconversion efficiency determination through the current–potential (J – V) curves that cannot be directly used due to the reported hysteresis.⁵ Another electrical technique extensively used for the characterization of photovoltaic devices, especially on sensitized and organic solar cells, is impedance spectroscopy (IS).⁶ This Viewpoint aims to clarify some general aspects of IS characterization, focusing on the special characteristic of PSCs in order to obtain reliable data that can allow a fair comparison between different devices.

IS is a nondestructive electrical characterization method that can be implemented coupled with device illumination in order to characterize the solar cells under working conditions. Usually, IS is a small-voltage perturbation method where a DC potential establishes the stationary condition of the device and a small AC signal at different frequencies is applied. Consequently, IS allows complete device analysis at the working conditions decoupling the different physical processes with different characteristic times (frequencies).⁶ This fact makes IS significantly appealing for characterization because, potentially, different physical processes can be analyzed by a single measurement. On the other hand, the experimental setup is simple and the measurements are easy to perform. However, to fully benefit from the IS potentiality, a complete model of the device, conventionally formulated in terms of an equivalent circuit in which each element has a physical meaning, is needed. While this model is well-known for other kinds of devices,⁶ it is not completely established for PSCs. Nevertheless, IS has been extensively used for the characterization of PSC,^{7–24} as some parts of the spectra have been identified as recombination resistance, geometrical capacitance, or accumulation capacitance, allowing a quantitative analysis. The interpretation of IS measurements for PSCs is beyond the scope of this Viewpoint

that focus on the experimental setup, measurements, and special considerations for PSCs.

IS measurements need the accomplishment of three fundamental conditions: (i) causality; (ii) linearity; and (iii) stability. Causality indicates that the measured response is due exclusively to the applied stimulus. To this extent, it is necessary to screen the sample from external perturbations; the standard procedure is to perform the IS measurements inside of a Faraday cage. Connection wires also need an appropriate electrical shielding to reduce significantly the electrical noise. Moreover, IS is based on the linearization of voltage and current equations considering that small perturbations over the voltage produces linear variations over the current.⁶ AC perturbation has to be high enough to produce a noise-free signal but small enough to ensure linearity. There is no universal rule, and the accomplishment of these conditions will depend on the sample and on the measurement conditions. A clear example is depicted in Figure 1a. While the measurement of a PSC at a DC bias, V_{appl} , of 0.2 V and AC perturbation of 50 mV can be realized with a good linear approach, the condition of linearity is not fulfilled for $V_{\text{appl}} = 0.8$ V at the same AC perturbations. The increase of AC perturbation produces a higher response and consequently a better signal/noise ratio. Figure 1b shows the impedance pattern of the cell analyzed in Figure 1a at $V_{\text{appl}} = 0.2$ V and different AC perturbation. As linearity is preserved in a tolerable manner even for relatively large AC perturbation, the main effect of the increase of the AC perturbation is the positive reduction of the electrical noise. Conversely, the same analysis performed at $V_{\text{appl}} = 0.8$ V (see Figure 1c) shows that the augmentation of AC perturbation does not just reduce the noise but also alters the result of the measurement due to loss in linearity.

Electrical noise can be especially significant at low frequencies. Unlike in the case of other photovoltaic technologies such as Si solar cells,²⁵ where no physical processes with long characteristic times (small frequencies) are present, for PSCs it is important to obtain noise-free measurements at low frequency as slow processes occur in PSCs.²⁶ In fact, this part of the spectrum is important to determine recombination resistance^{8,9} or accumulation capacitance.^{18,21} There are different ways to reduce the noise during the IS measurements: (i) the increase of AC while linearity is not disturbed, as we have already discussed, (ii) the increase of the integration time, and/or (iii) the increase of the number of integration cycles during the measurement. While the former has the drawback of altering the linearity, the two latter increase

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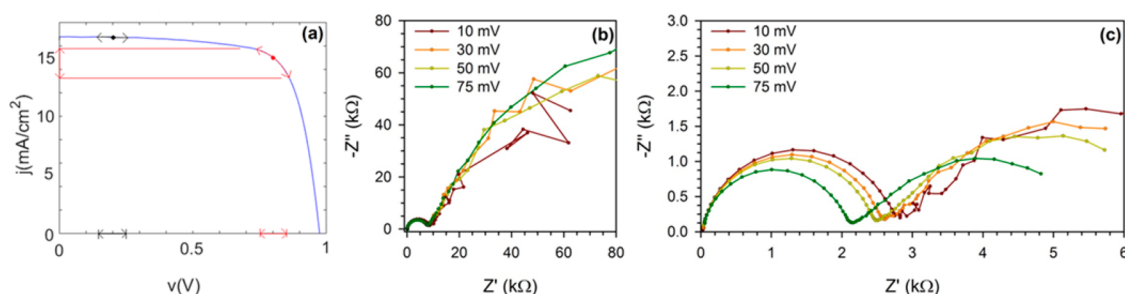


Figure 1. (a) J - V curve of a PSC with $\text{CH}_3\text{NH}_3\text{PbI}_3$ as the active layer. The variation of the current in terms of an modulated AC voltage of 50 mV is plotted for $V_{\text{appl}} = 0.2$ and 0.8 V. AC perturbation effect on the Nyquist plot for measurements of the same sample under 1 sun illumination, measured for a frequency range of 1 MHz to 0.1 Hz with $V_{\text{appl}} =$ (b) 0.2 and (c) 0.8 V. Details about PSCs fabrication can be found in the [Supporting Information](#).

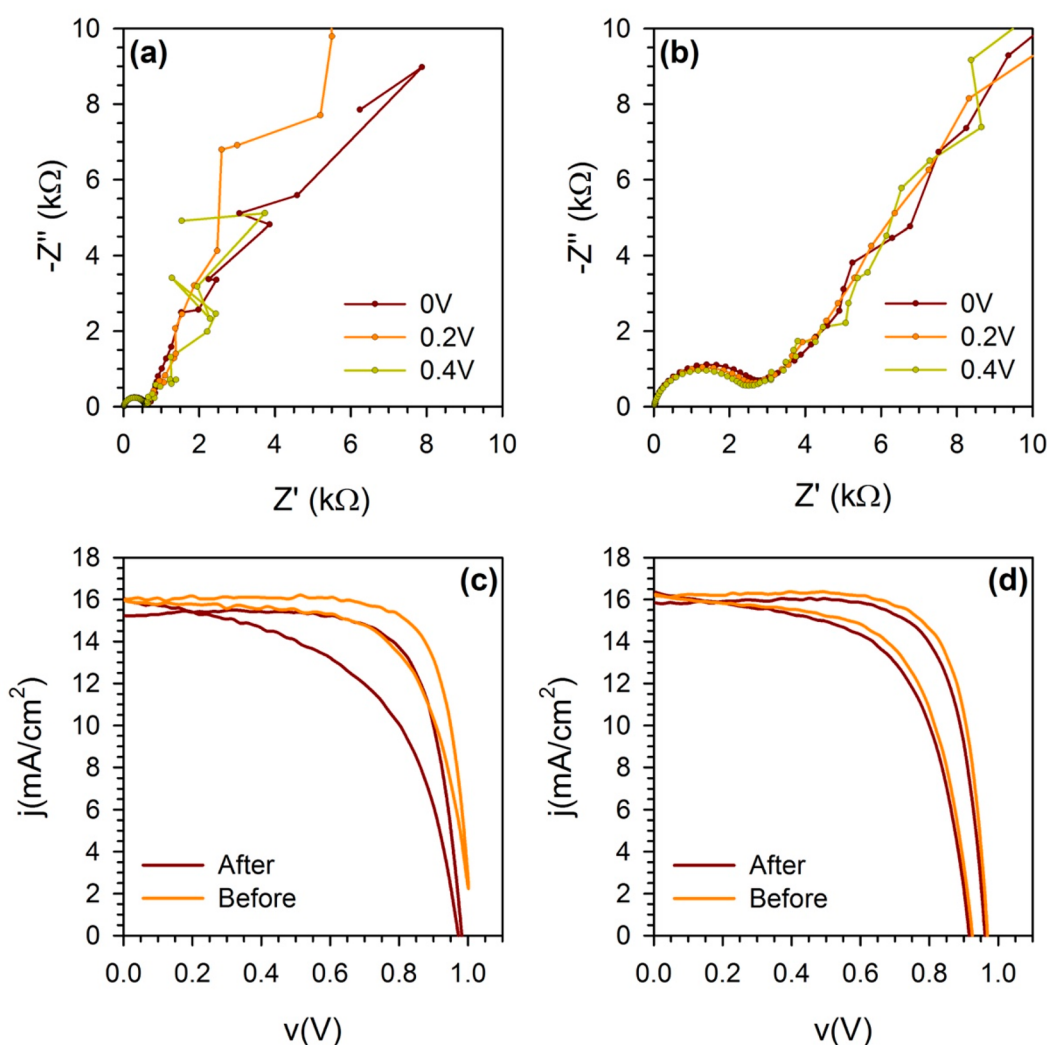


Figure 2. Nyquist plot at different V_{appl} of the same PSC under (a) 1 sun and (b) 0.1 sun light intensity. J - V curves with forward and reverse scans, corresponding to lower and higher apparent efficiencies, respectively, under 1 sun before and after the IS measurement at (c) 1 sun and (d) 0.1 sun light intensity.

the measurement time and could affect the third fundamental condition for IS measurement, the stability. As the scope of the IS measurement is to characterize the PSCs under stable working conditions, we suggest decreasing the measurement time as much as possible; consequently, the increment of integration time or the number of integration cycles is not advisable for low-stability samples. The use of dynamic AC

perturbation, larger at low V_{appl} , where noise is higher and linearity easier to fulfill, and smaller close to the open-circuit voltage, V_{oc} , where the linearity condition is more demanding, is recommended; see [Figure 1](#).

The major current challenge of PSCs is to increase their stability. There are multiple factors affecting the perovskite stability such as moisture, temperature, the nature of the

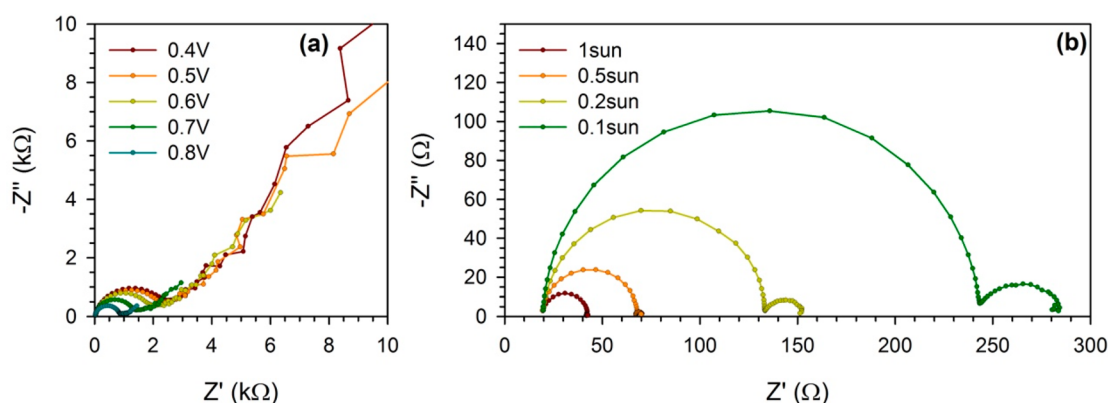


Figure 3. (a) Voltage scan under 0.1 sun and (b) light intensity scan at V_{oc} , with 60 frequencies measured in the 1 MHz–0.1 Hz frequency range in both cases.

selective contacts, the grain size, or light exposure.² The stability of PSCs has increased significantly since their origin, and some perovskite configurations, such as as multiple cations,^{23,27} inorganic perovskites,²² or 2D/3D layered perovskites, exhibit significant stability,²⁸ even under illumination at the maximum power point.^{29,30} However, this Viewpoint aims to give a set of experimental procedures valid in the most general cases of PSCs, and long IS measurement can produce degradation of certain perovskite devices. Even if this process is enhanced under illumination,³¹ it is important to carry out the measurements of PSCs under illumination conditions as perovskite properties change dramatically under illumination.^{21,32} Although IS at 1 sun illumination conditions can be used to reconstruct the J – V curve in the standard conditions for efficiency measurements,^{9,22} it is not necessary to carry out the IS measurements under 1 sun if IS aims at doing a comparative analysis between samples. For example, the analysis under 0.1 sun conditions, on one hand, brings the system to a high enough illumination to exhibit characteristic illumination features such as low-frequency accumulation capacitance^{18,21} and, on the other hand, reduces the electrical noise (compare panels (a) and (b) in Figure 2) and increases the device stability during measurement. The stability of the PSC can be quickly verified by comparing the J – V curves before and after IS measurement (see Figure 2c,d). It can be appreciated that after IS at different applied voltages under 1 sun illumination the variation of the J – V curve is significantly higher than that at 0.1 sun. It is important to highlight that the J – V curve just after impedance measurement can produce a false impression of cell degradation due to the poling conditioning; we suggest measuring J – V after different times to determine if the sample recovers its previous performance value (see Figure S1), allowing confidence in IS measurement as cell degradation is avoided.

There are several extrinsic procedures that contribute to increase the stability during the IS measurement, such as the use of a controlled temperature and atmosphere or encapsulation of the devices. In addition, there are also other intrinsic procedures for IS measurement conditions that can be used for this purpose that always have to be properly balanced to ensure the reliability of the measurement and the usefulness of the obtained data. A decrease of measurement time is beneficial in terms of stability, but it cannot be decreased by reducing excessively the low-frequency range, which is the most time-consuming, as important information is extracted from this range, as discussed above. We suggest using a frequency

range starting at the highest frequency of the equipment setup and extending at least down to 0.1 Hz. Of course, this frequency range could depend on the exact nature of each sample; for example, 0.1 Hz could be too high for a correct determination of DC resistance in samples with large low-frequency resistance or presenting negative capacitance in the low or intermediate frequency range.^{7,11,22} An alternative is to reduce the total number of frequencies for a single V_{appl} ; see Figures S2 and S3. In most cases, 40 frequencies distributed logarithmically in a frequency range between 1 MHz and 0.1 Hz should be enough to obtain detailed impedance data.

Finally, it is important to avoid a practice unfortunately extended in the literature: the comparison of IS spectra of different samples at just a single condition, generally at V_{oc} . This kind of characterization does not allow a fair comparison because the Fermi level splitting is not the same in most cases.⁶ The carrier density depends exponentially on the Fermi levels. Meanwhile, important cell parameters such as the recombination rate, chemical capacitance, or conductivity depend on the carrier density. Different samples can present a shift of energy levels, causing, even at the same V_{appl} , different conditions of Fermi level splitting to be reached. This fact is well-known in sensitized solar cells.⁶ Consequently, appropriate comparison has to be performed, sweeping the Fermi level splitting, either by fixing the illumination and applying different V_{appl} (see Figure 3a) or by using different illumination power densities, making a single spectrum at each illumination at the corresponding V_{oc} (see Figure 3b). When illumination is fixed (Figure 3a), different applied biases between the short circuit and open circuit should be applied, while when illumination is changed it has to be varied over several orders of magnitude due to the exponential dependence between the Fermi level and the illumination power density. The latter could be more stressing from the stability point of view due to the spectra recorded at high illumination compared with a voltage scan at low illumination (see Figure 2) but can allow analysis of the ideality factor in parallel to IS measurements.³³

In both cases, shown in Figure 3, a set of parameters at different Fermi level splitting can be obtained after the spectra fitting. One must note that when we speak about IS measurement we do not refer to obtaining a single impedance spectrum but refer to acquiring a complete set of spectra as in Figure 3. Depending on the experimental setup and settings, it will take 0.5–1 h, being demanding conditions in terms of stability for certain PSCs devices.

Table 1. Summary of the Common Problems Arising during the IS Measurement of Perovskites Solar Cells^a

problem	solution	drawback	good practice
noise (causality)	Faraday cage	none	to do systematically
	connection wire: electrical shielding	none	to do systematically
	increase AC	possible linearity loss	adjust AC with V_{appl}
	increase integration time	increase the measurement time	reduce the number of frequency points
	increase the number of integration cycles	increase the measurement time	reduce the number of frequency points
stability (cell evolution upon measurement)	adjust the lowest frequency measured	low-frequency part of the spectra must remain analyzable	
	reduce the number of frequency points/decade	the spectra must remain analyzable	-follow V_{oc} after each measurement (constant illumination)
	control temperature, use dry atmosphere, encapsulate	none	-measure $J-V$ before and after IS at different times
stability and noise	reduce the illumination power density	for measurements at various V_{appl}	

^aPossible solutions with their implied drawbacks and good practice suggestions are included.

In summary, this Viewpoint provides some suggestions about good practices regarding IS measurements as to avoid the comparison of a single spectrum and compare a set of spectra at various Fermi level splittings by changing the applied bias or the illumination intensity. IS measurements have to ensure causality, linearity, and stability and at the same time provide low-noise useful data. Good shielding and performing measurements in a Faraday cage will contribute to warranty causality. Stability can be improved by controlling the measurement atmosphere and temperature by device encapsulation and also by reducing the measurement time. However, low-frequency data are important for appropriate characterization of PSCs, and as a consequence, the measurement time cannot be reduced dramatically. To that end, illumination conditions can be moderated and/or the number of total frequency points reduced. The noise of the measurement can be lowered with no further increase of measurement time by increasing the AC perturbation. The use of a dynamic AC stimulus larger at low applied voltage and lower at higher voltages can ensure the linearity conditions. The stability of the devices during the measurement has to be verified in order to be confident with the obtained data. The stability can be followed by recording the V_{oc} between the measurements at various V_{appl} . Also measuring the $J-V$ curves before and after the impedance measurements can be a good proof of stability, knowing the recovery phenomenon that we have shown in this paper. Table 1 summarizes that careful IS measurements will allow one to obtain a set of reliable data for accurate PSC characterization.

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■ ASSOCIATED CONTENT

● Supporting Information

The Supporting Information is available free of charge on the ACS Publications website at DOI: 10.1021/acsenerylett.8b00465.

Experimental section, $J-V$ curves before and after IS measurements at different times to test degradation, comparison of the voltage scan at fixed illumination, and an illumination scan at V_{oc} with a different number of frequencies measured and their corresponding $J-V$ curves before and after the measurements (PDF)

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Notes

Views expressed in this Viewpoint are those of the authors and not necessarily the views of the ACS.

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SUPPORTING INFORMATION

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Experimental Section

TiO₂ compact layer: SnO₂:F (FTO) substrates were sonicated sequentially in distilled water with soap, distilled water, ethanol and propanol-2 for 15 minutes and then treated with an UV (ultraviolet)–O₃ lamp for 15 minutes. The TiO₂ compact layer was deposited by spray pyrolysis at 450 °C, consuming 5 ml of a solution of titanium di-isopropoxidebis (acetylacetonate, 75% vol. 2-propanol) in absolute ethanol (1:9, v/v ratio); the films were annealed at 450 °C for 30 minutes.

TiO₂ mesoporous layer: TiO₂ mesoporous was spin coated on TiO₂ compact layers at 2000 rpm for 10s from TiO₂ paste (Dyesol 30NRd, 30 nm average particle size) dissolved in absolute ethanol (150 mg/ml). The films were pre-heated at 100 °C for 10 minutes and then at 450 °C for 30 minutes.

Lithium treatment: TiO₂ mesoporous layers were treated with lithium by depositing a thin layer of bis-trifluoromethylsulfonamide lithium (35 mM in acetonitrile) at 3000 rpm for 10s. After spinning, samples were annealed at 450 °C for 30 minutes.

Perovskite deposition: Perovskite solution of 1.35M was prepared by dissolving PbI₂ and methylammonium iodine (MAI) in a mixture of dimethylformamide (DMF) and dimethyl sulfoxide (DMSO) with a molar ratio 1 PbI₂ : 1 MAI : 0.75 DMSO. Perovskite layer was coated on TiO₂ mesoporous treated lithium by spin coating 50 µl of perovskite solution at 4000 rpm, then annealed at 100°C for 3 minutes. The deposition was carried out inside a glove box filled with nitrogen.

SpiroOMeTAD and Gold: SpiroOMeTAD solution was prepared by dissolving 72.3 mg of spiro-OMeTAD(2,2',7,7'-tetrakis(N,N-di-p-methoxyphenylamine)-9,9-spirobifluorene) in 1 ml of chlorobenzene, then mixed with 28.8 µl of 4-tert-butylpyridine and 17.5 µl of a stock Li⁺ solution (which contained 520 mg/ml bis-trifluoromethylsulfonamide lithium salt in acetonitrile). Spiro OMeTAD layer was spin coated on perovskite films at 4000 rpm for 30s. Finally, 60 nm of gold were thermally evaporated in an ultrahigh vacuum chamber on top of SpiroOMeTAD layer to make complete devices.

Perovskite Solar Cell Characterizations: The active electrode area of 0.25 cm^2 per pixel is defined by the FTO and the Au contacts. Current density– voltage J–V curves were recorded under AM 1.5 100 mW/cm^2 simulated sunlight (ABET Technologies Sun 2000) previously calibrated with an NREL-calibrated Si solar cell. The impedance spectroscopy measurements were carried out in a PGSTAT- 30 potentiostat from Autolab. A Xe lamp was used to illuminate the PSC controlling the light intensity with neutral filters, between 0.1 and 100 mW/cm^2 . The AC voltage perturbation was varied in Figure 1. In Figure 2 and 3, the AC stimulus was varied depending on the applied voltage 20 mV under open-circuit conditions and 40 mV for voltage scan measurement at short circuit and with 0.2 V applied voltage. AC perturbation was 30 mV for 0.3 V of applied voltage. For applied voltages equal or higher than 0.4 V the AC signal was 20 mV . The integration time was fixed at 0.125 s and the number of cycles was equal to 1. Each frequency spectrum was measured ranging between 1 MHz and 0.1 Hz .

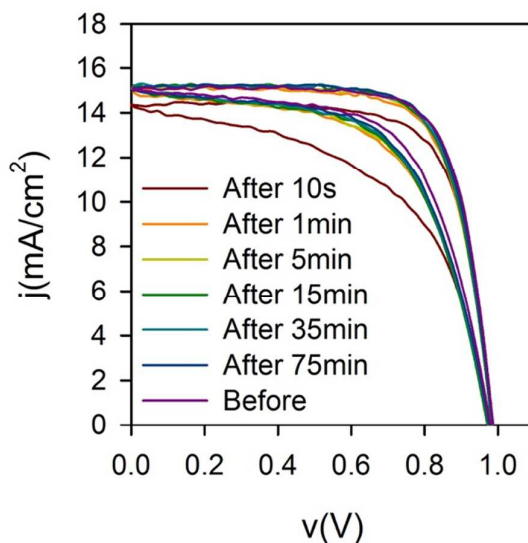


Figure S1: Time evolution of J-V curves before and after IS measurement (at 10 different voltages with 60 frequencies at each voltage in a 1 MHz - 0.1 Hz frequency range under 1 sun illumination. After the impedance measurements, the cell was kept in the dark for various times. J-V curves with forward and reverse scans, corresponding to lower and higher apparent efficiencies, respectively, under 1 sun before and after the IS measurement.

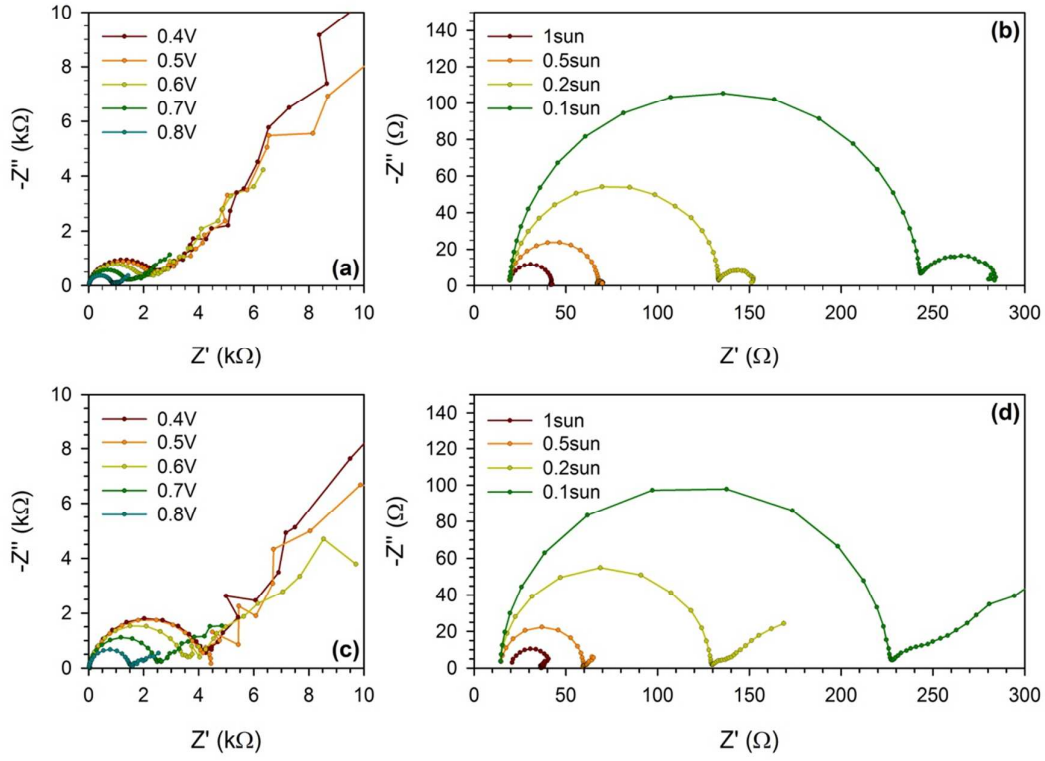


Figure S2: 1 MHz-0.1 Hz frequency range (a) Voltage scan under 0.1 sun with 60 frequencies measured at each V_{appl} with the corresponding J-V curves before and after IS measurement in Figure S3a. (b) Illumination scan with $V_{appl}=V_{oc}$ at each condition with 60 frequencies measured at each V_{appl} with the corresponding J-V curves before and after IS measurement in Figure S3b. (c) Voltage scan under 0.1 sun with 40 frequencies measured at each V_{appl} with the corresponding J-V curves before and after IS measurement in Figure S3c. (d) Illumination scan with $V_{appl}=V_{oc}$ at each condition with 40 frequencies measured at each V_{appl} with the corresponding J-V curves before and after IS measurement in Figure S3d.

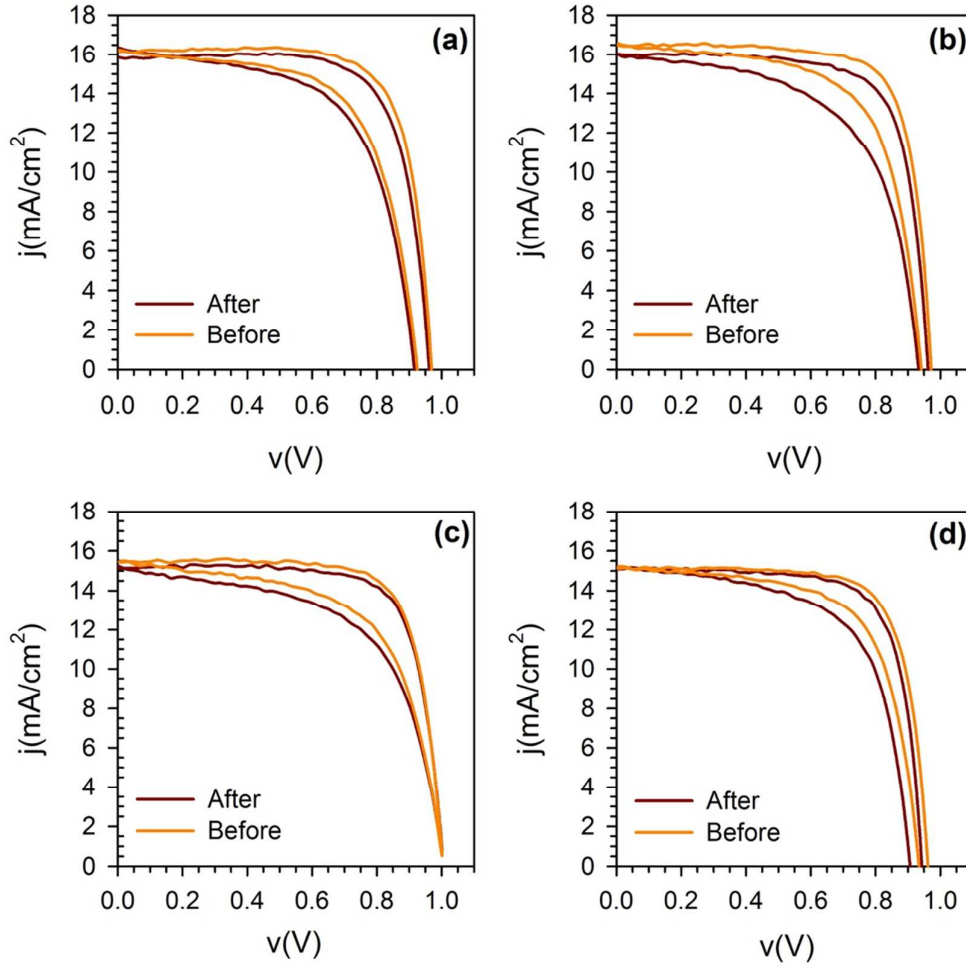


Figure S3: 1 MHz-0.1 Hz frequency range, J-V curves before and after IS **(a)** Voltage scan under 0.1 sun with 60 frequencies measured at each V_{appl} corresponding to Figure S2a. **(b)** Illumination scan with $V_{appl}=V_{oc}$ at each condition with 60 frequencies measured at each V_{appl} corresponding to Figure S2b. **(c)** Voltage scan under 0.1 sun with 40 frequencies measured at each V_{appl} corresponding to Figure S2c. **(d)** Illumination scan with $V_{appl}=V_{oc}$ at each condition with 40 frequencies measured at each V_{appl} corresponding to Figure S2d. J-V curves with forward and reverse scans, corresponding to lower and higher apparent efficiencies, respectively, under 1 sun before and after the IS measurement.